Noninverting 3-State Buffer

The MC74VHC1G125 is an advanced high speed CMOS noninverting 3-state buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power

The internal circuit is composed of three stages, including a buffered 3-state output which provides high noise immunity and stable output. The MC74VHC1G125 input structure provides protection when voltages up to 7.0 V are applied, regardless of the supply voltage. This allows the MC74VHC1G125 to be used to interface 5.0 V circuits to 3.0 V circuits.



- These are Pb-Free Devices

- at 1'A = 25°C

 Balanced Propagation Delays

 Pin and Function Compatible with Other Standard Logic Families

 Chip Complexity: FETs = 58; Equivalent Gates = 15

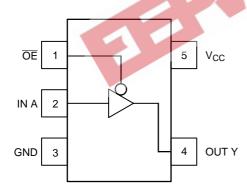


Figure 1. Pinout (Top View)



Figure 2. Logic Symbol



http://onsemi.com

MARKING DIAGRAMS

SC-88A/SOT-353/SC-70 **DF SUFFIX** CASE 419A



d = Date Code

TSOP-5/SOT-23/SC-59 **DT SUFFIX CASE 483**



Pin 1

d = Date Code

PIN ASSIGNMENT					
1	ŌĒ				
2	IN A				
3	GND				
4	OUT Y				
5	V _{CC}				

FUNCTION TABLE

A Input	OE Input	Y Output
L,	L	L
Н	L	Н
X	Н	Z

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol	Ch	aracteristics	Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage		-0.5 to +7.0	V
V _{OUT}	DC Output Voltage	$V_{CC} = 0$ High or Low State	-0.5 to 7.0 -0.5 to V _{CC} + 0.5	V
I _{IK}	Input Diode Current		-20	mA
I _{OK}	Output Diode Current	V_{OUT} < GND; V_{OUT} > V_{CC}	+20	mA
l _{OUT}	DC Output Current, per Pin		+25	mA
I _{CC}	DC Supply Current, V _{CC} and GND		+50	mA
P_{D}	Power Dissipation in Still Air	SC-88A, TSOP-5	200	mW
$\theta_{\sf JA}$	Thermal Resistance	SC-88A, TSOP-5	333	°C/W
T _L	Lead Temperature, 1 mm from Cas	e for 10 s	260	°C
TJ	Junction Temperature Under Bias		+150	°C
T _{stg}	Storage Temperature		-65 to +150	°C
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 1) Machine Model (Note 2) Charged Device Model (Note 3)	> 2000 > 200 N/A	V
I _{LatchUp}	LatchUp Performance	Above V _{CC} and Below GND at 125°C (Note 4)	± 500	mA

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. Tested to EIA/JESD22-A114-A.
- 2. Tested to EIA/JESD22-A115-A.
- 3. Tested to JESD22-C101-A.
- Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics		Min	Max	Unit
V _{CC}	DC Supply Voltage		2.0	5.5	V
V _{IN}	DC Input Voltage		0.0	5.5	V
V _{OUT}	DC Output Voltage		0.0	V _{CC}	V
T _A	Operating Temperature Range		- 55	+125	°C
t _r , t _f	Input Rise and Fall Time	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0	100 20	ns/V

Device Junction Temperature versus Time to 0.1% Bond Failures

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

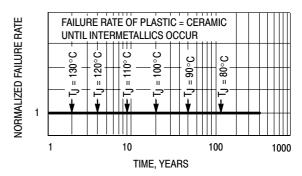


Figure 3. Failure Rate vs. Time Junction Temperature

DC ELECTRICAL CHARACTERISTICS

			v _{cc}	7	Γ _A = 25°(3	$T_A \le$	85°C	-55 ≤ T _A	≤ 125°C	
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V _{IH}	Minimum High–Level Input Voltage		2.0 3.0 4.5 5.5	1.5 2.1 3.15 3.85			1.5 2.1 3.15 3.85		1.5 2.1 3.15 3.85		V
V _{IL}	Maximum Low–Level Input Voltage		2.0 3.0 4.5 5.5			0.5 0.9 1.35 1.65		0.5 0.9 1.35 1.65		0.5 0.9 1.35 1.65	V
V _{OH}	Minimum High-Level Output Voltage V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		1.9 2.9 4.4		V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -4 \text{ mA}$ $I_{OH} = -8 \text{ mA}$	3.0 4.5	2.58 3.94			2.48 3.80		2.34 3.66		V
V _{OL}	Maximum Low-Level Output Voltage V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \mu\text{A}$	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1		0.1 0.1 0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$	3.0 4.5		21.	0.36 0.36	8-	0.44 0.44		0.52 0.52	V
l _{OZ}	Maximum 3–State Leakage Current	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$	5.5	36	为节	±0.25	Cr.	± 2.5		± 2.5	μΑ
I _{IN}	Maximum Input Leakage Current	V _{IN} = 5.5 V or GND	0 to 5.5	130	CO	±0.1		±1.0		±1.0	μΑ
I _{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			1.0		20		40	μΑ

AC ELECTRICAL CHARACTERISTICS C_{load} = 50 pF, Input t_r = t_f = 3.0 ns

		1	1	T _A = 25°C	;	T _A ≤	85°C	-55 ≤ T _A	≤ 125°C	
Symbol	Parameter	Test Conditions	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Maximum Propagation Delay, Input A to Y	$V_{CC} = 3.3 \pm 0.3 \text{ V C}_{L} = 15 \text{ pF}$ $C_{L} = 50 \text{ pF}$		4.5 6.4	8.0 11.5		9.5 13.0		12.0 16.0	ns
	(Figures 3 and 4)	$V_{CC} = 5.0 \pm 0.5 \text{ V C}_{L} = 15 \text{ pF}$ $C_{L} = 50 \text{ pF}$		3.5 4.5	5.5 7.5		6.5 8.5		8.5 10.5	
t _{PZL} , t _{PZH}	Maximum Output Enable Time, Input OE to Y	$V_{CC} = 3.3 \pm 0.3 \text{ V C}_{L} = 15 \text{ pF}$ $R_{L} = 1000 \Omega$ $C_{L} = 50 \text{ pF}$		4.5 6.4	8.0 11.5		9.5 13.0		11.5 15.0	ns
	(Figures 4 and 5)	$V_{CC} = 5.0 \pm 0.5 \text{ V C}_{L} = 15 \text{ pF}$ $R_{L} = 1000 \Omega$ $C_{L} = 50 \text{ pF}$		3.5 4.5	5.1 7.1		6.0 8.0		8.5 10.5	
t _{PLZ} , t _{PHZ}	Maximum Output Disable Time, Input OE to Y	$\begin{array}{c} \text{V}_{\text{CC}} = 3.3 \pm 0.3 \; \text{V} \; \; \text{C}_{\text{L}} = 15 \; \text{pF} \\ \text{R}_{\text{L}} \; 1000 \; \Omega \qquad \qquad \text{C}_{\text{L}} = 50 \; \text{pF} \end{array}$		6.5 8.0	9.7 13.2		11.5 15.0		14.5 18.0	ns
	(Figures 4 and 5)	$V_{CC} = 5.0 \pm 0.5 \text{ V C}_{L} = 15 \text{ pF}$ $R_{L} = 1000 \Omega$ $C_{L} = 50 \text{ pF}$		4.8 7.0	6.8 8.8		8.0 10.0		10.0 12.0	
C _{IN}	Maximum Input Capacitance			4.0	10		10		10	pF
C _{OUT}	Maximum 3-State Out- put Capacitance (Output in High Impedance State)			6.0						pF

		Typical @ 25°C, V _{CC} = 5.0 V	
C_{PD}	Power Dissipation Capacitance (Note 5)	8.0	pF

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

SWITCHING WAVEFORMS

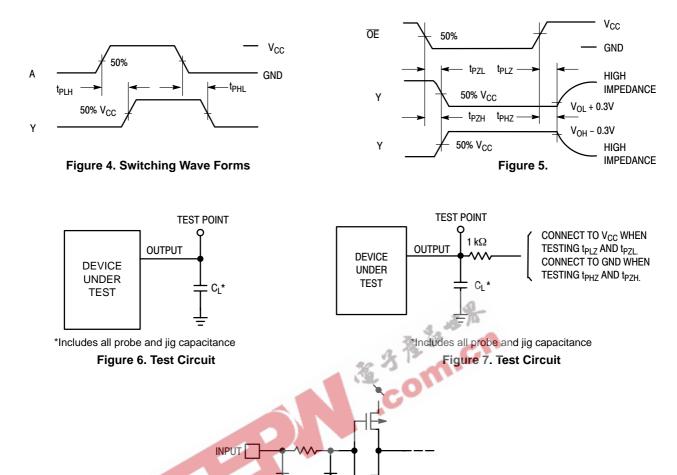


Figure 8. Input Equivalent Circuit

DEVICE ORDERING INFORMATION

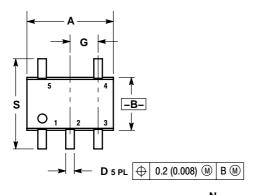
DEVICE ORDERING IN CRIMATION									
	Device Nomenclature								
Device Order Number	Circuit Indicator	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type (Name/SOT#/ Common Name)	Tape and Reel Size [†]	
MC74VHC1G125DFT1	МС	74	VHC1G	125	DF	T1	SC-88A/SOT-353 /SC-70	178 mm (7") 3000 Unit	
MC74VHC1G125DFT1G	МС	74	VHC1G	125	DF	T1	SC-88A/SOT-353 /SC-70 (Pb-Free)	178 mm (7") 3000 Unit	
MC74VHC1G125DFT2	МС	74	VHC1G	125	DF	T2	SC-88A/SOT-353 /SC-70	178 mm (7") 3000 Unit	
MC74VHC1G125DFT2G	МС	74	VHC1G	125	DF	T2	TSC-88A/SOT-353 /SC-70 (Pb-Free)	178 mm (7") 3000 Unit	
MC74VHC1G125DTT1	МС	74	VHC1G	125	DT	T1	TSOP-5/SOT-23 /SC-59	178 mm (7") 3000 Unit	
MC74VHC1G125DTT1G	МС	74	VHC1G	125	DT	T1	TSOP-5/SOT-23 /SC-59 (Pb-Free)	178 mm (7") 3000 Unit	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SC70-5/SC-88A/SOT-353 **DF SUFFIX**

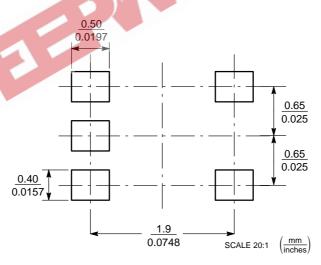
5-LEAD PACKAGE CASE 419A-02 ISSUE G



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65	BSC
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20

SOLDERING FOOTPRINT*

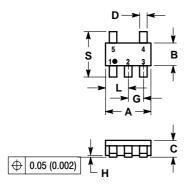


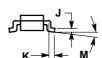
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOT23-5/TSOP-5/SC59-5 **DT SUFFIX**

5-LEAD PACKAGE CASE 483-02 **ISSUE C**

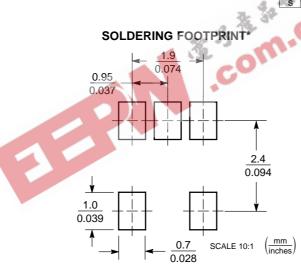




NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD
- THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 A AND B DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	2.90	3.10	0.1142	0.1220	
В	1.30	1.70	0.0512	0.0669	
С	0.90	1.10	0.0354	0.0433	
D	0.25	0.50	0.0098	0.0197	
G	0.85	1.05	0.0335	0.0413	
Н	0.013	0.100	0.0005	0.0040	
J	0.10	0.26	0.0040	0.0102	
K	0.20	0.60	0.0079	0.0236	
L 🦸	1.25	1.55	0.0493	0.0610	
M	0	10	0	10	
S	2.50	3.00	0.0985	0.1181	



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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